# INTEGRATED CIRCUITS



Product specification

1996 Aug 28

IC24 Data Handbook



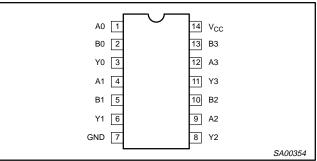


## 74LVT32

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}C;$ GND = 0V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An, Bn to Yn	$C_L = 50 pF;$ $V_{CC} = 3.3 V$	2.6 3.2	ns
C <sub>IN</sub>	Input capacitance	V <sub>I</sub> = 0V or 3.0V	3	pF
I <sub>CCL</sub>	Total supply current	Outputs Low; $V_{CC} = 3.6V$	1	mA

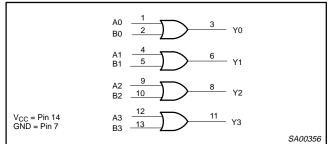
#### **PIN CONFIGURATION**



#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 4, 5, 9, 10, 12, 13	An, Bn	Data inputs
3, 6, 8, 11	Yn	Data outputs
7	GND	Ground (0V)
14	V <sub>CC</sub>	Positive supply voltage

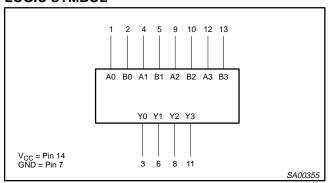
#### LOGIC DIAGRAM



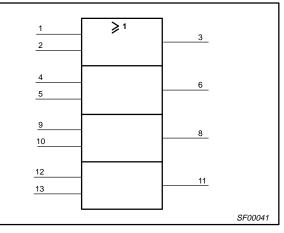
#### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER		
14-Pin Plastic SO	–40°C to +85°C	74LVT32 D	74LVT32 D	SOT108-1		
14-Pin Plastic SSOP	–40°C to +85°C	74LVT32 DB	74LVT32 DB	SOT337-1		
14-Pin Plastic TSSOP	–40°C to +85°C	74LVT32 PW	74LVT32PW DH	SOT402-1		

#### LOGIC SYMBOL



#### LOGIC SYMBOL (IEEE/IEC)



#### **FUNCTION TABLE**

INPUTS		OUTPUT
Dna	Dnb	Qn
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

NOTES:

H = High voltage level L = Low voltage level

### 74LVT32

#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

SYMBOL	PARAMETER	PARAMETER CONDITIONS		UNIT	
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V	
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-50	mA	
VI	DC input voltage <sup>3</sup>		-0.5 to +7.0	V	
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA	
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	Output in Off or High state	-0.5 to +7.0	V	
		Output in High state	-32		
IOUT	DC output current	Output in Low state	64	- mA	
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C	

NOTES:

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the 1. device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction 2.

The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER		LIMITS		
STMBOL		MIN	MAX	UNIT	
V <sub>CC</sub>	DC supply voltage	2.7	3.6	V	
VI	Input voltage	0	5.5	V	
V <sub>IH</sub>	High-level input voltage			V	
V <sub>IL</sub>	Low-level Input voltage		0.8	V	
I <sub>OH</sub>	High-level output current		-20	mA	
I <sub>OL</sub>	Low-level output current		32	mA	
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10	ns/V	
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C	

74LVT32

#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to GND (ground = 0V)

			LIMITS Temp = -40°C to +85°C			UNIT	
SYMBOL	PARAMETER	TEST CONDITIONS					
			MIN	TYP <sup>1</sup>	MAX	1	
V <sub>IK</sub>	Input clamp voltage	V <sub>CC</sub> = 2.7V; I <sub>IK</sub> = -18mA			-1.2	V	
		$V_{CC} = 2.7$ to 3.6V; $I_{OH} = -100\mu A$	V <sub>CC</sub> -0.2				
V <sub>OH</sub>	High-level output voltage	$V_{CC} = 2.7V; I_{OH} = -6mA$	2.4			V	
		$V_{CC} = 3.0V; I_{OH} = -20mA$	2.0			1	
		V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 100µA			0.2	V	
V <sub>OL</sub>	Low-level output voltage	V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 24mA			0.5		
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 32mA			0.5		
I.	Input lookage ourrent	V <sub>CC</sub> = 0 or 3.6V; V <sub>I</sub> = 5.5V			10		
łı	Input leakage current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or } GND$			±1	μA	
I <sub>OFF</sub>	Output off current	$V_{CC} = 0V$ ; $V_{I}$ or $V_{O} = 0$ to 4.5V			±100	μA	
I <sub>CCH</sub>	Quiescent supply current	$V_{CC}$ = 3.6V; Outputs High, $V_{I}$ = GND or $V_{CC}$ , $I_{O}$ = 0			0.02	mA	
I <sub>CCL</sub>		$V_{CC}$ = 3.6V; Outputs Low, $V_{I}$ = GND or $V_{CC,}$ $I_{O}$ = 0		1	2		
$\Delta I_{CC}$	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 3V to 3.6V; One input at V_{CC} –0.6V, Other inputs at V_{CC} or GND			0.2	μΑ	
CI	Input capacitance	$V_{I} = 3V \text{ or } 0$		3		pF	

#### NOTES:

1. All typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C. 2. This is the increase in supply current for each input at the specificed voltage level other than  $V_{CC}$  or GND.

#### **AC CHARACTERISTICS**

GND = 0V;  $t_R = t_F = 2.5ns$ ;  $C_L = 50pF$ ,  $R_L = 500\Omega$ ;  $T_{amb} = -40^{\circ}C$  to +85°C.

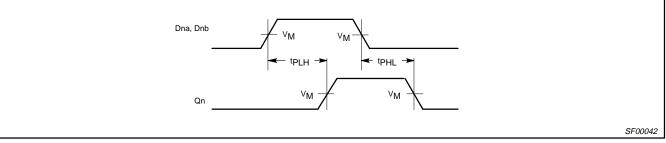
SYMBOL PARAMETER			LIMITS					
		WAVEFORM	Vcc	$V_{CC}=3.3V\pm0.3V$			UNIT	
			MIN	TYP <sup>1</sup>	MAX	MAX		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An, Bn to Yn	1	1.0 1.0	2.6 3.2	3.8 4.6	4.5 4.9	ns	

NOTE:

1. All typical values are at V\_{CC} = 3.3V and T\_{amb} = 25^{\circ}C.

#### AC WAVEFORMS

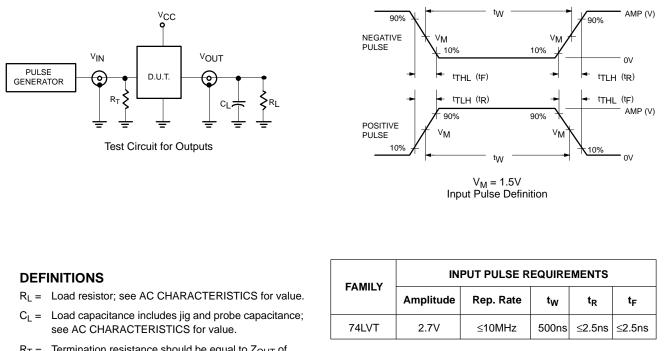
 $V_{M}$  = 1.5V,  $V_{IN}$  = GND to 2.7V



Waveform 1. Propagation delay for inverting outputs

## 74LVT32

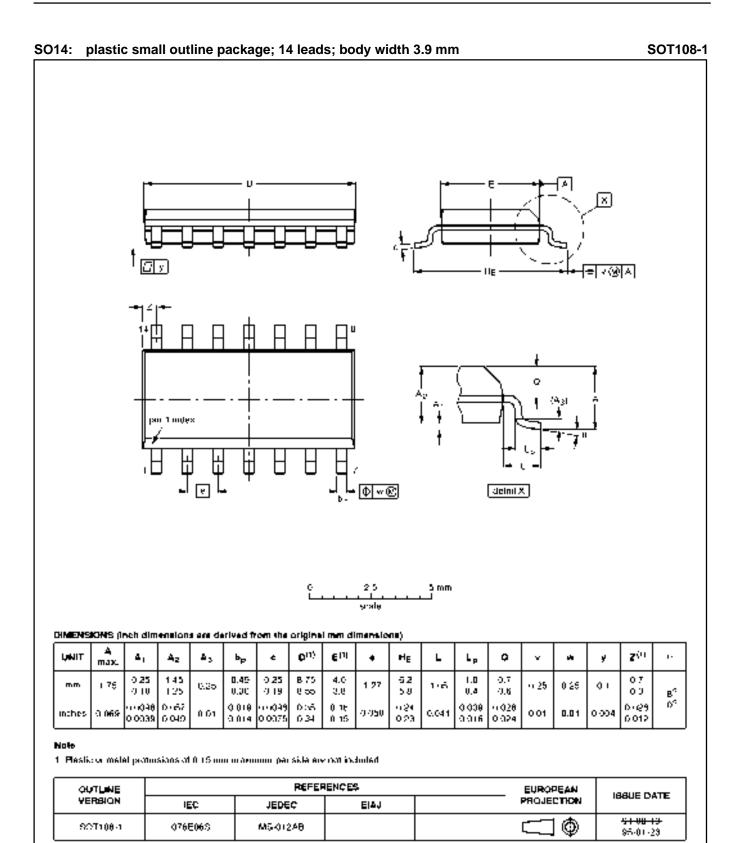
#### **TEST CIRCUIT AND WAVEFORMS**



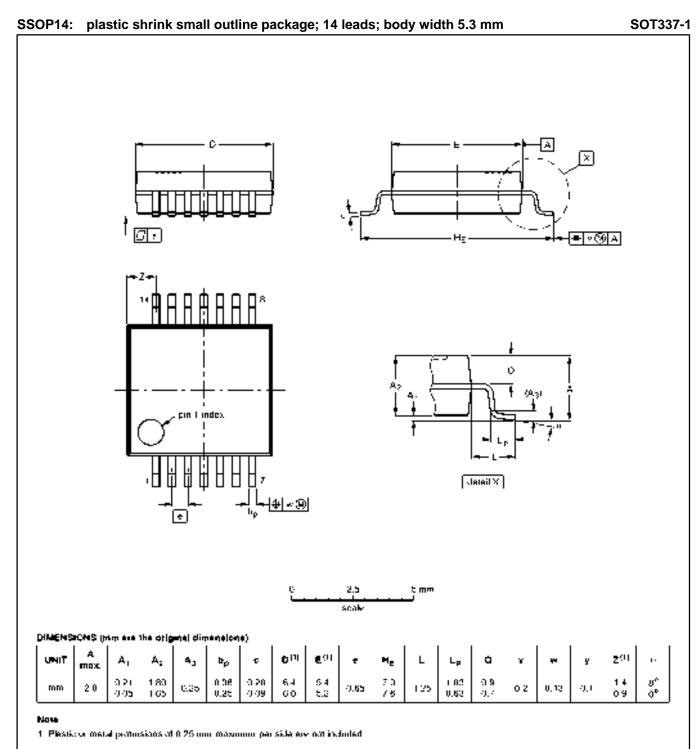
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 $R_T$  = Termination resistance should be equal to  $Z_{OUT}$  of pulse generators.

### 74LVT32

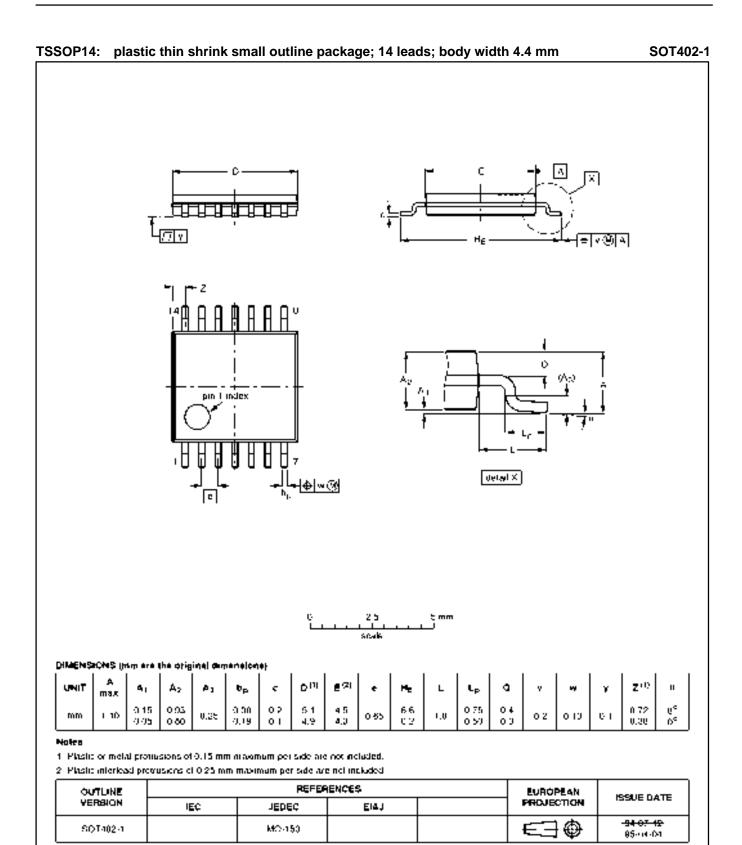


### 74LVT32



OUTLINE		REFER	IENCES	EUROPEAN	188UE DATE
VERBION	IEC	JEDEC	EIT	PROJECTION	IDOUE DWIE
SOT007-1		MO-150AB		€∃�	<del>-95-82-94</del> 96-01-19

### 74LVT32



74LVT32

NOTES

### 74LVT32

DEFINITIONS				
Data Sheet Identification Product Status Definition		Definition		
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.		
		This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.		
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.		

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